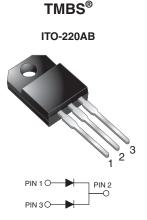
MBRF1090CT-M3, MBRF10100CT-M3

Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5.0 A			
V _{RRM}	90 V, 100 V			
I _{FSM}	120 A			
V _F	0.75 V			
T _J max.	150 °C			
Package	ITO-220AB			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS ($T_c = 25$ °C unless otherwise noted)						
PARAMETER		SYMBOL	MBRF1090CT	MBRF10100CT	UNIT	
Max. repetitive peak reverse voltage		V _{RRM}	90	100	V	
Working peak reverse voltage		V _{RWM}	90	100	V	
Max. DC blocking voltage		V _{DC}	90	100	V	
Max. average forward rectified current at T_C = 105 °C	total device	1	10		А	
	per diode	I _{F(AV)}	5.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	120		А	
Non-repetitive avalanche energy at $T_J = 25 \text{ °C}$, L = 60 mH per diode		E _{AS}	60		mJ	
Peak repetitive reverse current at t_p = 2 µs, 1 kHz, T _J = 38 °C ± 2 °C per diode		I _{RRM}	0.5		А	
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +150		°C	
Isolation voltage from terminal to heatsink with t = 1 min		V _{AC}	1500		V	

RoHS

COMPLIANT HALOGEN FREE

Document Number: 89126

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ELECTRICAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MBRF1090CT	MBRF10100CT	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 5.0 A	T _C = 125 °C	0.75		V	
	$I_{F} = 5.0 \text{ A}$	T _C = 25 °C	۷F	0.85		v
Maximum reverse current per diode at working peak reverse voltage ⁽²⁾		T _J = 25 °C	100		00	μA
		T _J = 100 °C	IR	6	.0	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25$ °C unless otherwise noted)						
PARAMETER	ER SYMBOL MBRF1090CT MBRF10100CT		MBRF10100CT	UNIT		
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	6.8		°C/W		

ORDERING INFORMATION (EXAMPLE)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	MBRF10100CT-M3/4W	1.75	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

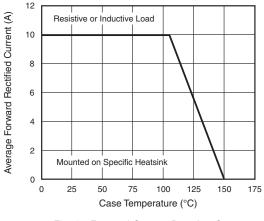


Fig. 1 - Forward Current Derating Curve

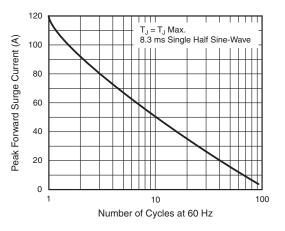


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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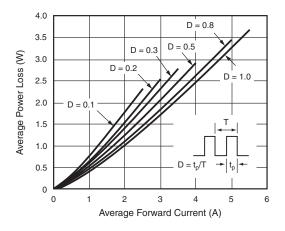


Fig. 3 - Forward Power Loss Characteristics Per Diode

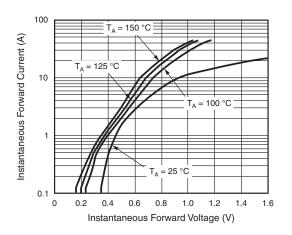


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

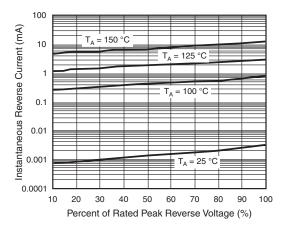


Fig. 5 - Typical Reverse Characteristics Per Diode

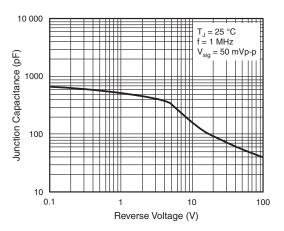


Fig. 6 - Typical Junction Capacitance Per Diode

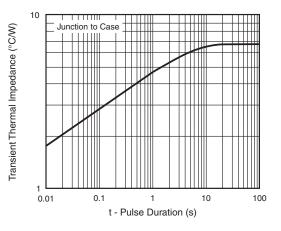


Fig. 7 - Typical Transient Thermal Impedance Per Diode

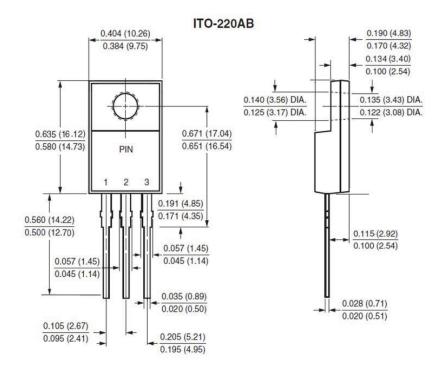
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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